# 16V Low Cost, High Performance CMOS Rail-to-Rail Operational Amplifiers AD8661/AD8662/AD8664

# **Preliminary Technical Data**

### **FEATURES**

Low Offset Voltage: 75 µV max Low Input Bias Currents 1pA Max Single-Supply Operation: 5 to 16 Volts Dual-Supply Operation: +/- 2.5 to +/-8 Volts Low Noise: 10 nV/√Hz Wide Bandwidth: 4 MHz Unity Gain Stable

### APPLICATIONS

Multi-pole Filters Sensors Medical Equipment Consumer Audio Photodiode amplification ADC driver

### **GENERAL DESCRIPTION**

The AD8661, AD8662 and AD8664 are single, dual and quad rail-to-rail output single supply amplifiers that use Analog Devices' patented DigiTrim® trimming technique to achieve low offset voltage. The AD8661 family features an extended operating range with supply voltages up to 16 V. They also feature low input bias currents, wide signal bandwidth, and low input voltage and current noise.

The combination of low offsets, very low input bias currents, and wide supply range make these amplifiers useful in a wide variety of applications normally associated with much higher priced JFET amplifiers. Systems utilizing high impedance sensors, such as photo-diodes benefit from the combination of low input bias current, low noise, low offset and bandwidth. The wide operating voltage range matches today's high performance ADCs and DACs. Audio applications and medical monitoring equipment can take advantage of the high input impedance, low voltage and current noise, wide bandwidth and the lack of "popcorn" noise (found in many other low input bias current amplifiers).

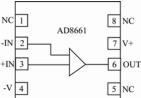
The AD8661, AD8662 and AD8664 are specified over the extended industrial (-40° to +125°C) temperature range. The AD8661, single, is available in the tiny 8-lead LFCSP (MO-220) 3mm x 3mm and 8-lead SOIC package. The AD8662, dual, is available in the 8-lead micro-SOIC and narrow SOIC surface mount packages. The AD8664, quad, is available in 14-lead TSSOP and narrow 14-pin SOIC packages.

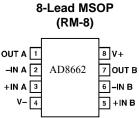
LFCSP, MSOP and TSSOP versions are available in tape and reel only.

### REV. PrA 10/5/2004

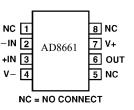
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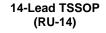
## PIN CONFIGURATIONS 8-Lead LFCSP 8-Le (CP-8) ( 3mm x 3mm





8-Lead SO (R-8)



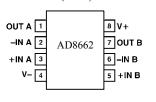


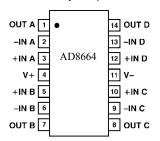
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	Þ	14 OUT D
-IN A 2		13 –IN D
+IN А	AD8664	12 +IN D
<b>V</b> + 4		11 V-
+IN B 5		10 +IN C
–IN B		9 –IN C
ОЛТ В 🛛		в оот с

14-Lead SO

(R-14)

8-Lead SO (R-8)





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# Preliminary Technical Data AD8661/AD8662/AD8664

# **ELECTRICAL CHARACTERISTICS** ( $V_{S}$ =+5.0V, $V_{CM}$ = $V_{S}/2$ , $T_{A}$ =+25°C unless otherwise noted)

noted)		1				
Parameter	Symbol	Conditions	Min	Тур	Max	Units
INPUT CHARACTERISTICS						
Offset Voltage	V <sub>OS</sub>	$V_{SY} = 8V, V_{CM} = 3V$			75	μV
		$V_{CM} = 0.1V$ to 3.0V		30	300	μV
		-40°< T <sub>A</sub> < +85°C			650	μV
		-40°< T <sub>A</sub> < +125°C			750	μV
Input Bias Current	I <sub>B</sub>			0.3	1	pА
	в	-40°< T <sub>A</sub> < +85°C		0.0	50	pA
		-40°< T <sub>A</sub> < +125°C			300	pA
		40 < 14 < 1120 0			000	pr
Input Offset Current	I <sub>OS</sub>			0.2	TBD	pА
		-40°< T <sub>A</sub> < +85°C			20	pА
		-40°< T <sub>A</sub> < +125°C			75	pА
Input Voltage Range			tbd		3.0	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = 0.1V$ to 3.0V	80	95		dB
Large Signal Voltage Gain	A <sub>VO</sub>	$R_L = 10 \text{ k}\Omega \text{ V}_O = 0.5 \text{V} \text{ to } 4.5 \text{V}$	70	100		V/mV
Offset Voltage Drift	$\Delta V_{OS} / \Delta T$			3	10	μV/°C
OUTPUT CHARACTERISTICS						
Output Voltage High	V <sub>OH</sub>	I <sub>L</sub> = 1mA	4.80	4.85		V
		I <sub>L</sub> = 10mA	4.80	4.85		V
		-40°C < T <sub>A</sub> < +125°C	4.75			V
Output Voltage Low	V <sub>OL</sub>	$I_{L} = 1 m A$		60	120	mV
	V <sub>OL</sub>	$I_L = 1mA$		60	120	mV
	0L	-40°C < T <sub>A</sub> < +125°C			150	mV
Output Current	I <sub>OUT</sub>	~		±19		mA
Closed Loop Output Impedance	Z <sub>OUT</sub>	f=1 MHz, $A_V = 1$		65		Ω
POWER SUPPLY	001					
Power Supply Rejection Ratio	PSRR	$V_{S} = 5 V$ to 16 V	80	95		dB
Supply Current/Amplifier	I <sub>SY</sub>	$V_{O} = 0V$		1.2	1.8	mA
		-40°< T <sub>A</sub> < +125°C			2.0	mA
DYNAMIC PERFORMANCE						
Slew Rate	SR	$R_L = 10 \ k\Omega$		3		V/µs
Settling Time	t <sub>s</sub>	To 0.1%, 0 V to 1V step		<1		μS
Gain Bandwidth Product	GBP			4		MHz
Phase Margin	Øo degrees	C <sub>L</sub> = 15 pF			60	
NOISE PERFORMANCE	uegiees					
Peak-to-Peak Noise	e <sub>n</sub> p-p	f=0.1Hz to 10 Hz		2.5		μV p-p
Voltage Noise Density	e <sub>n</sub>	f=1kHz		12		nV/√Hz
Voltage Noise Density	e <sub>n</sub>	f=10kHz		10		nV/√Hz
Current Noise Density	i <sub>n</sub>	f=1kHz		0.1		pA/√Hz
				0.1		

Gain Bandwidth Product

NOISE PERFORMANCE Peak-to-Peak Noise

Voltage Noise Density

Voltage Noise Density

**Current Noise Density** 

Phase Margin

GBP

e<sub>n</sub> p-p

 $C_L = 15 \text{ pF}$ 

f=1kHz

f=10kHz

f=1kHz

f=0.1Hz to 10 Hz

Øo

en

en

i<sub>n</sub>

# Preliminary Technical Data AD8661/AD8662/AD8664

4

60

2.5

12

10

0.1

# ELECTRICAL CHARACTERISTICS (V<sub>s=±8.0</sub>V, V<sub>cM</sub> = 0, T<sub>a</sub>=+25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Тур	Max	Units
INPUT CHARACTERISTICS						
Offset Voltage	V <sub>OS</sub>	$V_{SY} = 8V, V_{CM} = 3V$			75	μV
		$V_{CM} = -8.1V$ to +6.0V		30	300	μV
		-40°< T <sub>A</sub> < +85°C			650	μV
		-40°< T <sub>A</sub> < +125°C			750	μV
Input Bias Current	I <sub>B</sub>			0.3	1	pА
		-40°< T <sub>A</sub> < +85°C			50	pА
		-40°< T <sub>A</sub> < +125°C			300	pА
Input Offset Current	I <sub>OS</sub>			0.2	TBD	pА
		-40°< T <sub>A</sub> < +85°C			20	pА
		-40°< T <sub>A</sub> < +125°C			75	pА
Input Voltage Range			tbd		6	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = -8.1V$ to +6.0V	80	95		dB
Large Signal Voltage Gain	A <sub>VO</sub>	R <sub>L</sub> =10 kΩ V <sub>O</sub> = -7.5V to+7.5V	70	85		V/mV
Offset Voltage Drift	$\Delta V_{OS} / \Delta T$			3	10	μV/°C
OUTPUT CHARACTERISTICS	N/	1 1	7.00	7.05		
Output Voltage High	V <sub>OH</sub>	$I_L = 1mA$	7.90 7.6	7.95 7.7		VV
		$I_{L} = 10 \text{mA}$		1.1		V
		-40°C < T <sub>A</sub> < +125°C	7.4			V
Output Voltage Low	V <sub>OL</sub>	$I_L = 1mA$		-7.97	-7.93	mV
		I <sub>L</sub> = 10mA		-7.8	-7.7	mV
		-40°C < T <sub>A</sub> < +125°C			-7.5	mV
Output Current	I <sub>OUT</sub>			±140		mA
Closed Loop Output Impedance	Z <sub>OUT</sub>	f=1 MHz, $A_V = 1$		45		Ω
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	$V_{S} = 5V$ to 16V	80	95		dB
Supply Current/Amplifier	I <sub>SY</sub>	$V_{O} = 0V$		1.5	1.8	mA
		-40°< T <sub>A</sub> < +125°C			2.0	mA
DYNAMIC PERFORMANCE						
Slew Rate	SR	$R_L = 10 \text{ k}\Omega$		3		V/μs
Settling Time	t <sub>s</sub>	To 0.1%, 0 V to 1V step		<1		μS
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MHz

degrees

μV p-p

nV/√Hz

nV/√Hz

pA/√Hz

# AD8661/AD8662/AD8664

### ABSOLUTE MAXIMUM RATINGS<sup>1</sup>

Supply voltage+18V
Input Voltage
Differential Input Voltage±18V
Output Short-Circuit Duration to Gnd <sup>2</sup> Observe Derating Curves
Storage Temperature Range
R, CP, RM, RU Package65°C to +150°C
Operating Temperature Range
AD8661/AD8662/AD866440°C to +125°C
Junction Temperature Range
R, CP, RM, RU Package65°C to +150°C
Lead Temperature Range (Soldering, 60 Sec)+300°C

θJA	θJC	Units
		°C/W
210 158	45 43	°C/W °C/W
120	36	°C/W
180	35	°C/W
	210 158 120	11 10       210 45   158 43   120 36

NOTES

<sup>1</sup> Absolute maximum ratings apply at 25°C, unless otherwise noted.

 $^2~\theta_{JA}$  is specified for the worst-case conditions, i.e.,  $\theta_{JA}$  is specified for device soldered in circuit board for surface mount packages.

## ORDERING GUIDE

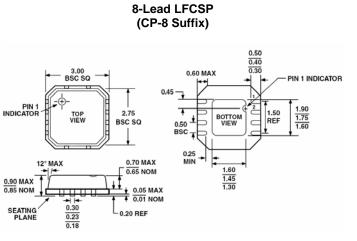
Model	Temperature Range	Package Description	Package Option	Branding Information
AD8661ACP	-40°C to +125°C	8-Pin LFCSP	CP-8	
AD8661ARZ	-40°C to +125°C	8-Pin SOIC	R-8	
AD8662ARMZ	-40°C to +125°C	8-Pin micro-SOIC	RM-8	
AD8662ARZ	-40°C to +125°C	8-Pin SOIC	R-8	
AD8664ARZ	-40°C to +125°C	14-Pin SOIC	R-14	
AD8664ARUZ	-40°C to +125°C	14-Pin TSSOP	RU-14	

### CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 1500 V readily accumulate on the human body and test equipment and can discharge without detection. Although this device features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high-energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



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14-Lead TSSOP

(RU-14)

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0.177 (4.50)

0.169 (4.30)

0.256 (6.50)

0.246 (6.25)

0.0079 (0.20)

0.0035 (0.090)

8° 0°

0.028 (0.70)

0.020 (0.50)

0.201 (5.10)

0.193 (4.90)

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H

0.0256

(0.65) BSC

PIN 1 🖊

0.006 (0.15)

0.002 (0.05)

41

SEATING PLANE

H

0.0118 (0.30)

0.0075 (0.19)

0.0433 (1.10) MAX

**OUTLINE DIMENSIONS** 

